DISCRETE SEMICONDUCTORS

DATA SHEET

BFQ67WNPN 8 GHz wideband transistor

Product specification

September 1995



BFQ67W

FEATURES

- · High power gain
- Low noise figure
- High transition frequency
- Gold metallization ensures excellent reliability
- SOT323 envelope.

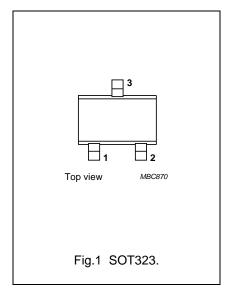
DESCRIPTION

NPN transistor in a plastic SOT323 envelope.

It is designed for wideband applications such as satellite TV tuners and RF portable communications equipment up to 2 GHz.

PINNING

PIN	DESCRIPTION		
	Code: V2		
1	base		
2	emitter		
3	collector		



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	_	20	V
V _{CEO}	collector-emitter voltage	open base	_	-	10	V
Ic	DC collector current		_	-	50	mA
P _{tot}	total power dissipation	up to T _s = 118 °C; note 1	_	-	300	mW
h _{FE}	DC current gain	$I_C = 15 \text{ mA}; V_{CE} = 5 \text{ V}; T_j = 25 ^{\circ}\text{C}$	60	100	-	
f _T	transition frequency	I_C = 15 mA; V_{CE} = 8 V; f = 2 GHz; T_{amb} = 25 °C	_	8	_	GHz
G _{UM}	maximum unilateral power gain	$I_c = 15 \text{ mA}; V_{CE} = 8 \text{ V}; f = 1 \text{ GHz}; $ $T_{amb} = 25 \text{ °C}$	_	13	_	dB
F	noise figure	$I_c = 5 \text{ mA}; V_{CE} = 8 \text{ V}; f = 1 \text{ GHz}$	_	1.3	_	dB

LIMITING VALUES

In accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	20	V
V _{CEO}	collector-emitter voltage	open base	_	10	V
V _{EBO}	emitter-base voltage	open collector	_	2.5	V
Ic	DC collector current		_	50	mA
P _{tot}	total power dissipation	up to T _s = 118 °C; note 1	_	300	mW
T _{stg}	storage temperature		-65	150	°C
T _i	junction temperature		_	175	°C

Note

1. T_s is the temperature at the soldering point of the collector tab.

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THERMAL RESISTANCE

SYMBOL	PARAMETER	CONDITIONS	THERMAL RESISTANCE
R _{th j-s}	thermal resistance from junction to soldering point	up to $T_s = 118$ °C; note 1	190 K/W

Note

1. $T_{\mbox{\scriptsize S}}$ is the temperature at the soldering point of the collector tab.

CHARACTERISTICS

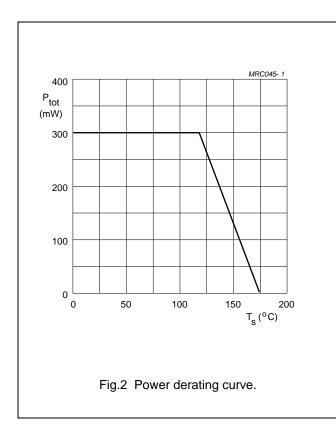
 $T_j = 25$ °C, unless otherwise specified.

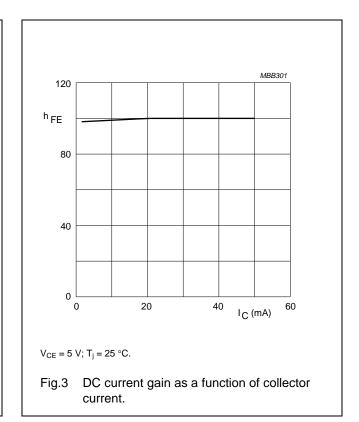
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector cut-off current	I _E = 0; V _{CB} = 5 V	_	-	50	nA
h _{FE}	DC current gain	I _C = 15 mA; V _{CE} = 5 V	60	100	_	
C _c	collector capacitance	$I_E = i_e = 0$; $V_{CB} = 8 \text{ V}$; $f = 1 \text{ MHz}$	_	0.7	_	pF
C _e	emitter capacitance	$I_C = I_C = 0$; $V_{EB} = 0.5 \text{ V}$; $f = 1 \text{ MHz}$	_	1.3	_	pF
C _{re}	feedback capacitance	I _C = 0; V _{CB} = 8 V; f = 1 MHz	_	0.5	_	pF
f _T	transition frequency	I_C = 15 mA; V_{CE} = 8 V; f = 2 GHz; T_{amb} = 25 °C	_	8	_	GHz
G _{UM}	maximum unilateral power gain (note 1)	I_C = 15 mA; V_{CE} = 8 V; f = 1 GHz T_{amb} = 25 °C	_	13	_	dB
		$I_C = 15 \text{ mA}; V_{CE} = 8 \text{ V}; f = 2 \text{ GHz}; $ $T_{amb} = 25 \text{ °C}$	_	8	_	dB
F	noise figure	$\Gamma_{\text{s}} = \Gamma_{\text{opt}}$; $I_{\text{C}} = 5$ mA; $V_{\text{CE}} = 8$ V; $f = 1$ GHz	_	1.3	_	dB
		$\Gamma_{\text{s}} = \Gamma_{\text{opt}}$; $I_{\text{C}} = 15$ mA; $V_{\text{CE}} = 8$ V; $f = 1$ GHz	_	2	_	dB
		$\Gamma_{\text{s}} = \Gamma_{\text{opt}}$; $I_{\text{C}} = 5$ mA; $V_{\text{CE}} = 8$ V; $f = 2$ GHz	_	2.2	-	dB
		$I_C = 5 \text{ mA}; V_{CE} = 8 \text{ V};$ $f = 2 \text{ GHz}; Z_s = 60 \Omega$	_	2.5	_	dB
		$\Gamma_{\text{s}} = \Gamma_{\text{opt}}$; $I_{\text{C}} = 15$ mA; $V_{\text{CE}} = 8$ V; $f = 2$ GHz	_	2.7	_	dB
		$I_C = 5 \text{ mA}; V_{CE} = 8 \text{ V};$ $f = 2 \text{ GHz}; Z_s = 60 \Omega$	_	3	_	dB

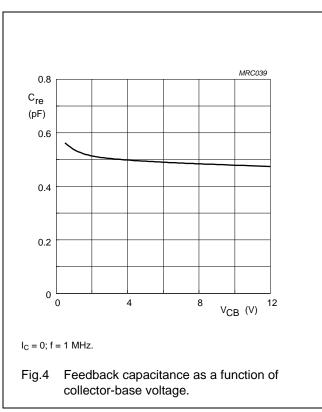
Note

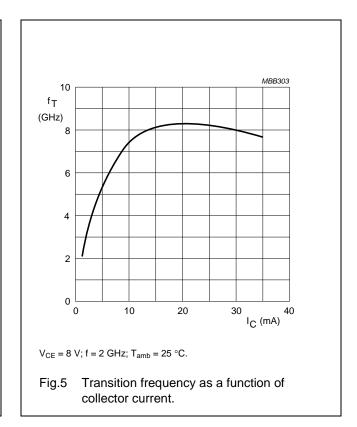
1. $\,G_{UM}$ is the maximum unilateral power gain, assuming S_{12} is zero and

$$G_{UM} = 10 \log \frac{\left|S_{21}\right|^2}{(1 - \left|S_{11}\right|^2)(1 - \left|S_{22}\right|^2)} dB.$$



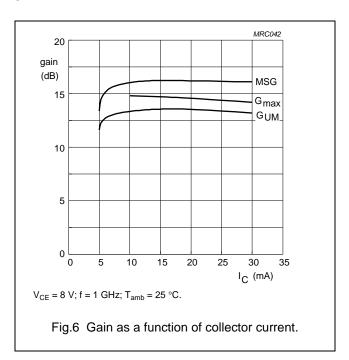


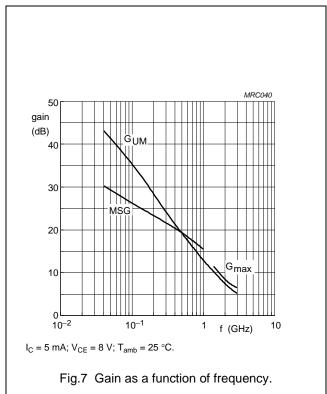


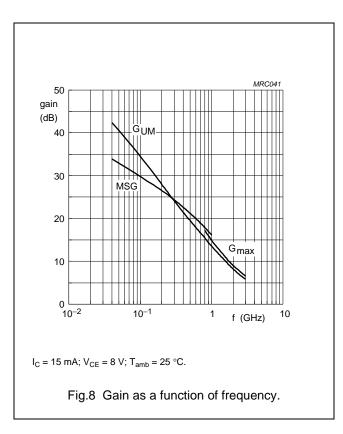


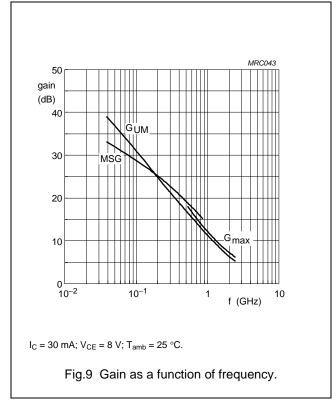
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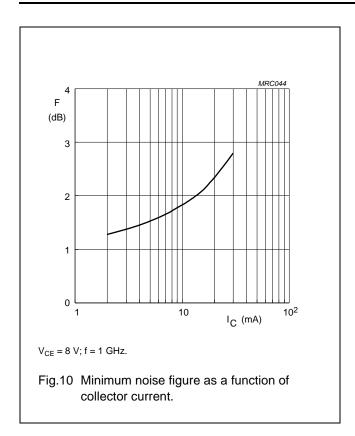
In Figs 6 to 9, G_{UM} = maximum unilateral power gain; MSG = maximum stable gain; G_{max} = maximum available gain.

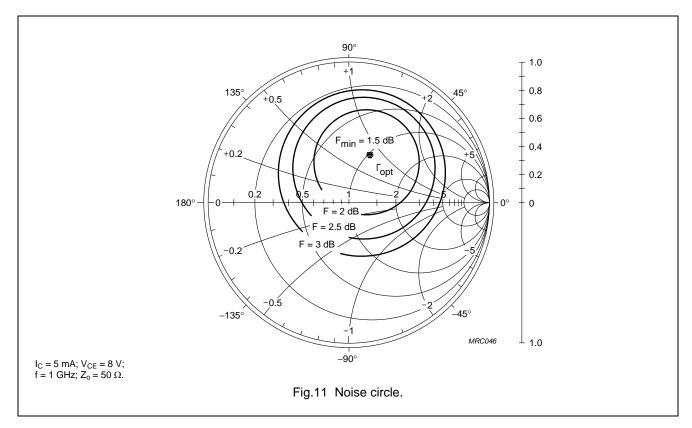




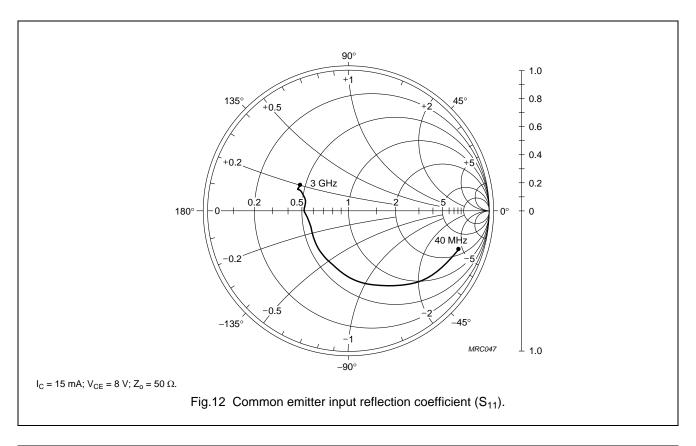


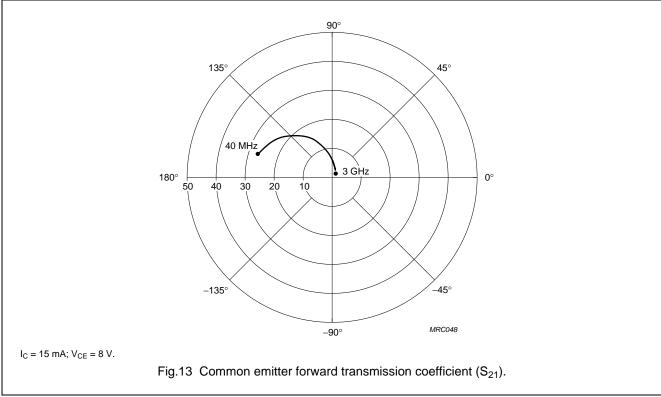




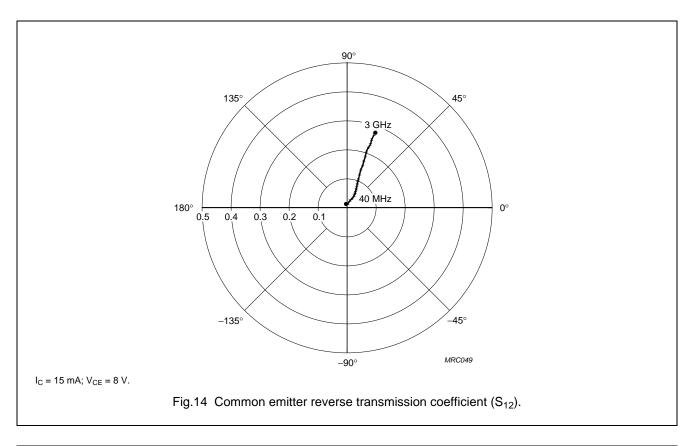


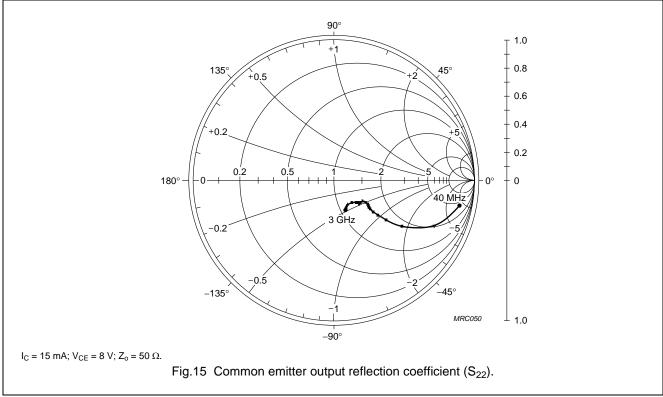
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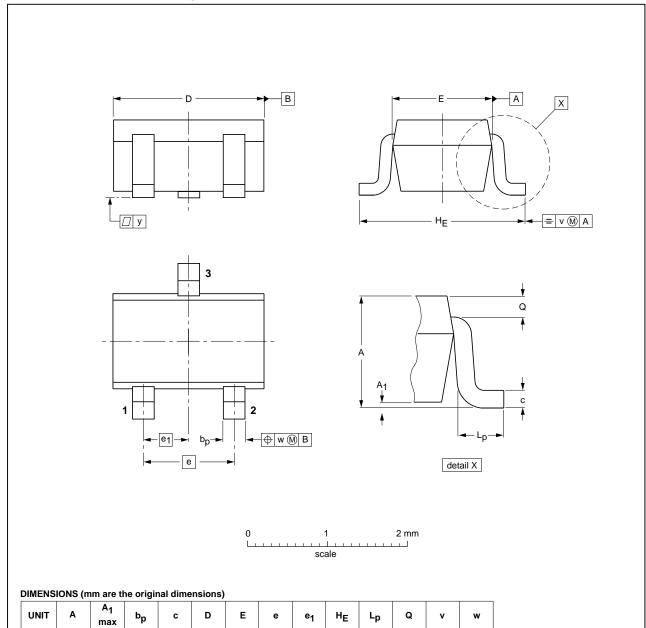


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PACKAGE OUTLINE

Plastic surface-mounted package; 3 leads

SOT323



OUTLINE	REFERENCES		EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT323			SC-70			-04-11-04 06-03-16

2.2 2.0

0.65

0.45

0.23

0.2

0.2

1.35 1.15

1.3

1.1 0.8

mm

0.1

0.4 0.3

0.25

0.10

2.2

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DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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